

PW3400A

30V N-Channel MOSFET

5.8A 30V; $R_{DS(ON)typ}=20m\Omega@10V$, $R_{DS(ON)typ}=22m\Omega@4.5V$,
 $R_{DS(ON)typ}=25m\Omega@2.5V$

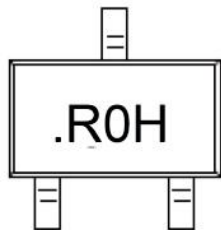
FEATURE

- TrenchFET Power MOSFET
- Excellent $R_{DS(on)}$ and Low Gate Charge

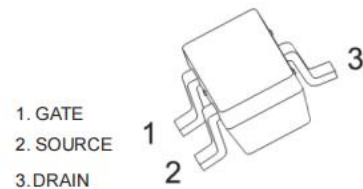
Application

- DC/DC Converter
- Load Switch for Portable Devices
- Battery Switch

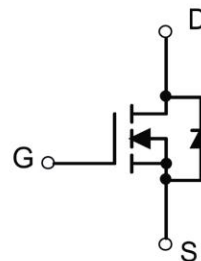
MARKING:



SOT-23-3L



Schematic diagram



ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current ^(1,5)	I_D	5.8	A
Pulsed Drain Current ⁽²⁾	I_{DM}	30	A
Power Dissipation ^(4,5)	P_D	1.8	W
Thermal Resistance from Junction to Ambient ⁽⁵⁾	$R_{\theta JA}$	69.4	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{STG}	-55~+150	$^\circ\text{C}$

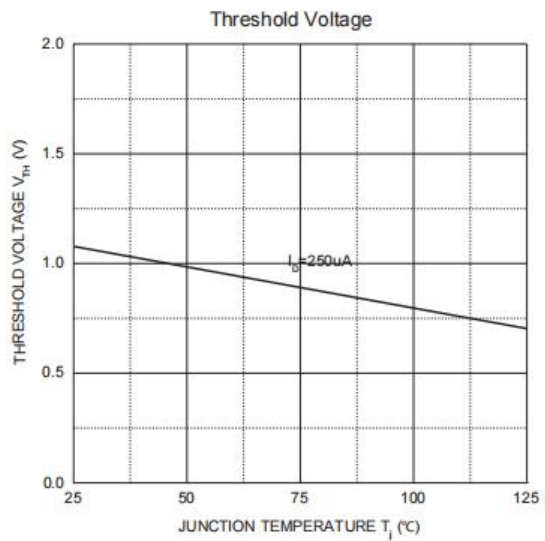
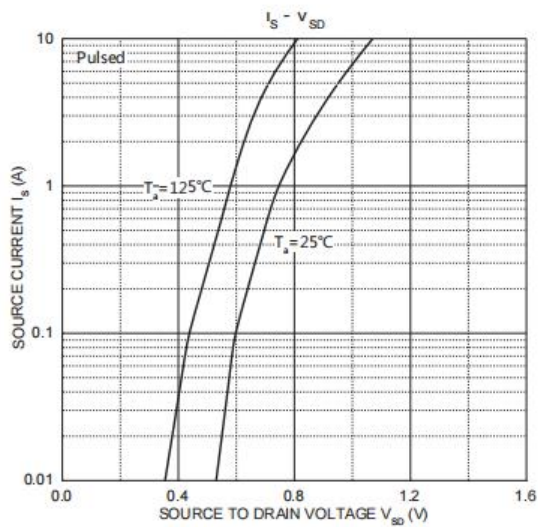
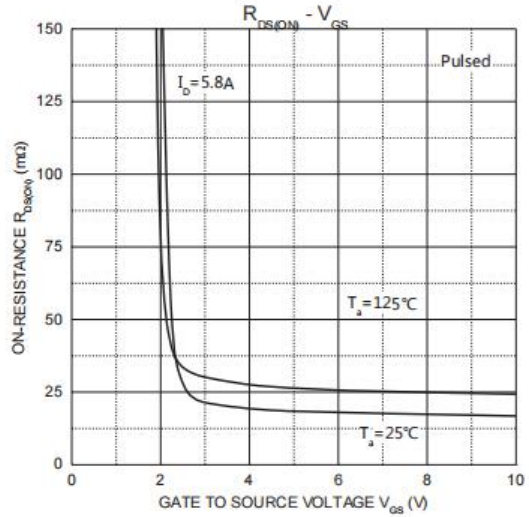
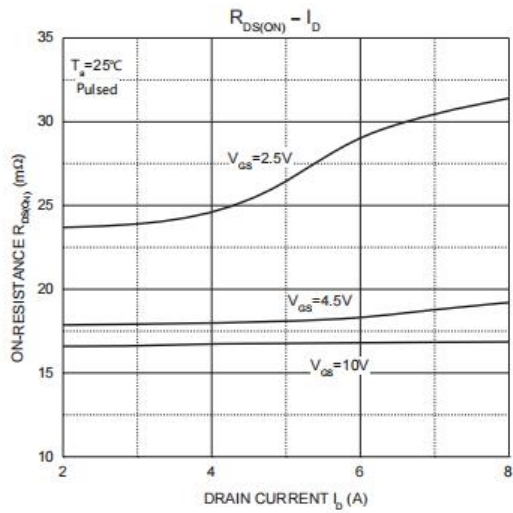
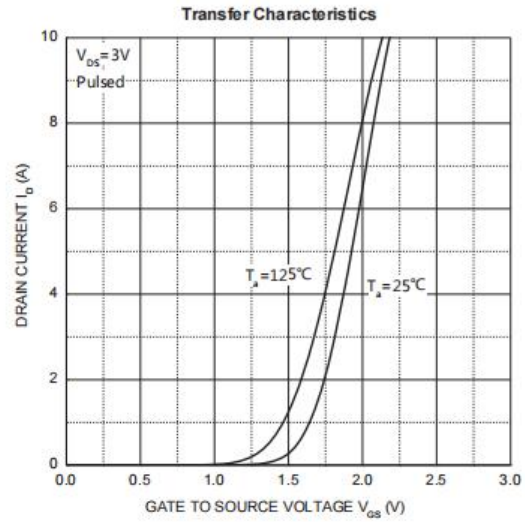
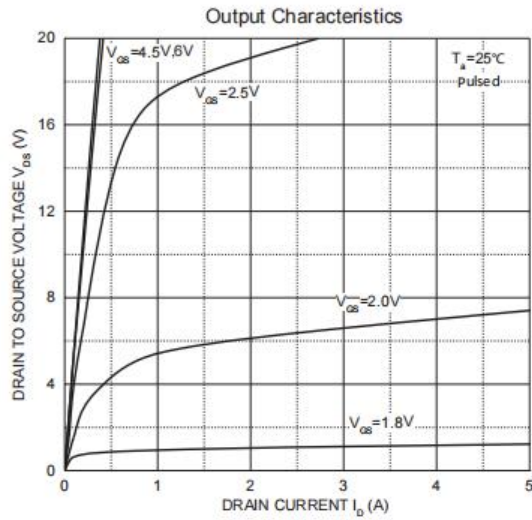
MOSFET ELECTRICAL CHARACTERISTICS(T_a=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =24V,V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±12V, V _{DS} = 0V			±0.1	μA
Gate threshold voltage ⁽³⁾	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.7	1.0	1.4	V
Drain-source on-resistance ⁽³⁾	R _{DS(on)}	V _{GS} =10V, I _D =5.8A		20	27	mΩ
		V _{GS} =4.5V, I _D =5A		22	30	
		V _{GS} =2.5V, I _D =4A		25	35	
Forward tranconductance ⁽³⁾	g _{FS}	V _{DS} =5V, I _D =5A	8			S
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	V _{DS} =15V,V _{GS} =0V,f=1MHz			1155	pF
Output Capacitance	C _{oss}			108		
Reverse Transfer Capacitance	C _{rss}			84		
Gate resistance	R _g	V _{DS} =0V,V _{GS} =0V,f =1MHz			3.6	Ω
SWITCHING CHARACTERISTICS						
Turn-on delay time	t _{d(on)}	V _{GS} =10V,V _{DS} =15V, R _L =2.7Ω,R _{GEN} =3Ω			5	ns
Turn-on rise time	t _r				7	
Turn-off delay time	t _{d(off)}				40	
Turn-off fall time	t _f				6	
SOURCE-DRAIN DIODE CHARACTERISTICS						
Body Diode Voltage ⁽³⁾	V _{DS}	I _S =1A, VGS = 0V			1	V

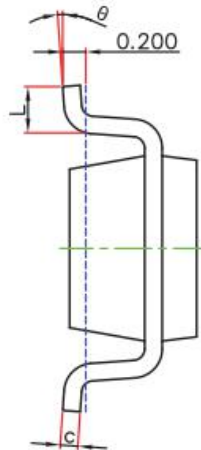
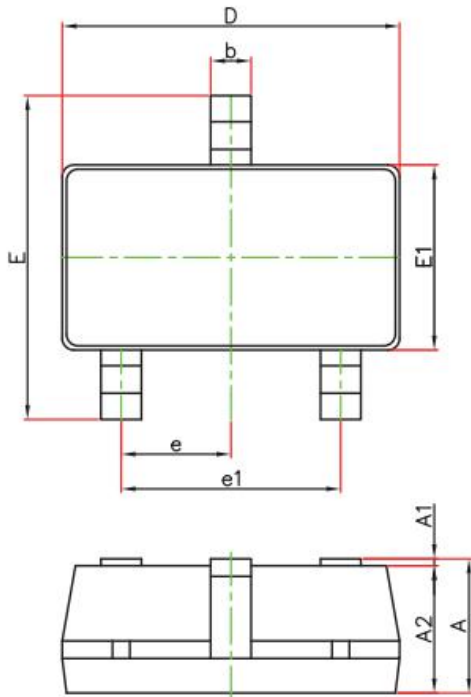
Notes:

1. The maximum current rating is limited by package.
2. Pulse Test : Pulse Width ≤ 10μs, duty cycle ≤ 1%.
3. Pulse Test : Pulse Width ≤ 300μs, duty cycle ≤ 2%.
4. The power dissipation P_D is limited by T_{J(MAX)} = 150°C.
5. Device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A = 25°C.

Typical Electrical and Thermal Characteristics



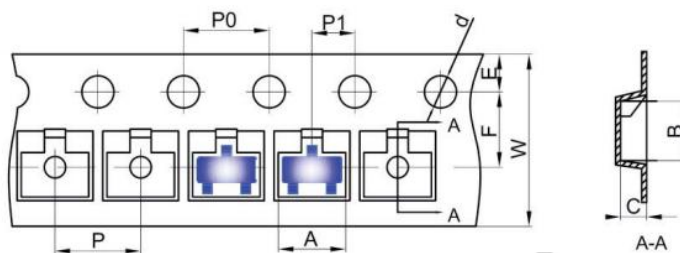
SOT-23-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

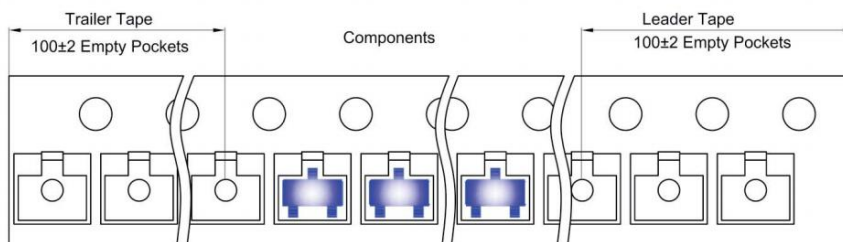
SOT-23-3L Tape and Reel

SOT-23-3L Embossed Carrier Tape

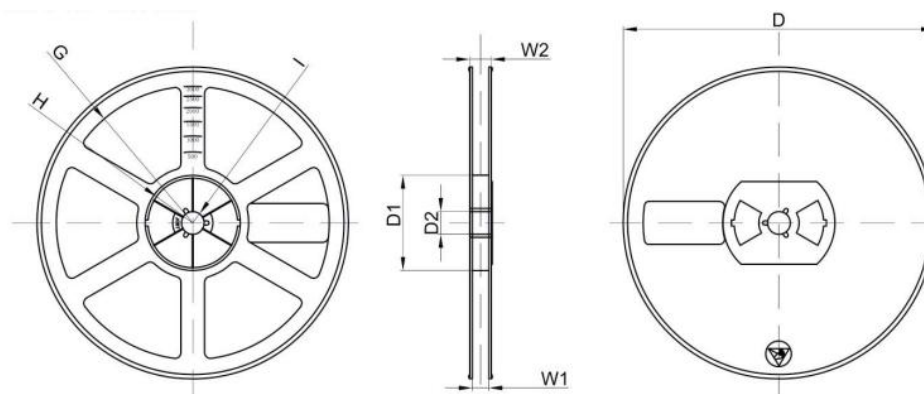


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23-3L	3.18	3.28	1.32	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23-3L Tape Leader and Trailer



SOT-23-3L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	